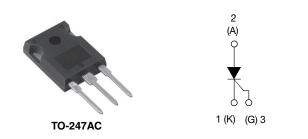
Vishay Semiconductors

High Voltage Phase Control Thyristor, 40 A



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PRODUCT SUMMARY								
Package	TO-247AC							
Diode variation	Single SCR							
I _{T(AV)}	35 A							
V _{DRM} /V _{RRM}	1600 V							
V _{TM}	1.45 V							
I _{GT}	150 mA							
TJ	- 40 °C to 125 °C							

FEATURES

- High voltage (up to 1600 V)
- Designed and qualified according to JEDEC-JESD47
- Compliant to RoHS Directive 2002/95/EC
- 125 °C max. operating junction temperature



• Halogen-free according to IEC 61249-2-21 definition (-M3 only)

APPLICATIONS

• Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-40TPS16... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS										
PARAMETER	TEST CONDITIONS	VALUES	UNITS							
I _{T(AV)}	Sinusoidal waveform	35	А							
I _{RMS}		55	~							
V _{RRM} /V _{DRM}		1600	V							
I _{TSM}		500	А							
V _T	40 A, T _J = 25 °C	1.45	V							
dV/dt		1000	V/µs							
dl/dt		100	A/µs							
TJ		- 40 to 125	°C							

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA					
VS-40TPS16PbF, VS-40TPS16-M3	1600	1700	10					

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ABSOLUTE MAXIMUM RATINGS	S					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current	I _{T(AV)}	$T_{\rm C}$ = 79 °C, 180° conduction half sine v	wave	35		
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}			55	A	
Maximum peak, one-cycle	L	10 ms sine pulse, rated V_{RRM} applied		500		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied		600		
Maximum 12t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied Initial $T_J = T_I$ maximum		1250	A ² s	
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied	1760	A-S		
Maximum I²√t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	12 500	A²√s		
Low level value of threshold voltage	V _{T(TO)1}		1.02	V		
High level value of threshold voltage	V _{T(TO)2}			1.23	v	
Low level value of on-state slope resistance	r _{t1}	T _J = 125 °C		9.74		
High level value of on-state slope resistance	r _{t2}			7.50	mΩ	
Maximum peak on-state voltage	V _{TM}	110 A, T _J = 25 °C		1.85	V	
Maximum rate of rise of turned-on current	dl/dt	T _J = 25 °C		100	A/µs	
Maximum holding current	Ι _Η		150			
Maximum latching current	١L		300			
		$T_J = 25 °C$,	0.5	mA	
Maximum reverse and direct leakage current	I _{RRM} /I _{DRM}	$T_J = 125 \text{ °C}$ $V_R = \text{Rated } V_{RRM}/V_R$	/DRM	10		
Maximum rate of rise of off-state voltage	dV/dt	$T_{\rm J}=T_{\rm J}$ maximum, linear to 80 % $V_{\rm DRM}$, R _g -k = Open	1000	V/µs	

TRIGGERING									
PARAMETER	SYMBOL	т	EST CONDITIONS	VALUES	UNITS				
Maximum peak gate power	P _{GM}			10	W				
Maximum average gate power	P _{G(AV)}			2.5	vv				
Maximum peak gate current	I _{GM}			2.5	А				
Maximum peak negative gate voltage	- V _{GM}			10					
Maximum required DC gate voltage to trigger		T _J = - 40 °C		4.0	v				
	V _{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	2.5					
voltage to trigger		T _J = 125 °C		1.7					
		T _J = - 40 °C		270					
Maximum required DC gate surrent to triager		T _J = 25 °C		150					
Maximum required DC gate current to trigger	I _{GT}	T _J = 125 °C		80	mA				
		$T_{\rm J} = 25 ^{\circ}{\rm C}$, for 40	40						
Maximum DC gate voltage not to trigger	V_{GD}	T 405 20 M Deleter		0.25	V				
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRN}	I = Maleu value	6	mA				

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THERMAL AND MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C				
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.6					
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W				
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.2					
Approvimato woight				6	g				
Approximate weight				0.21	oz.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
	maximum			12 (10)	(lbf · in)				
Marking device			Case style TO-247AC	40TF	PS16				

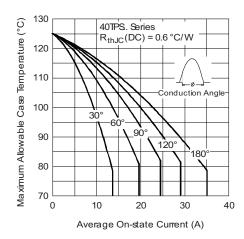


Fig. 1 - Current Rating Characteristics

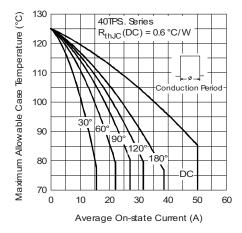


Fig. 2 - Current Rating Characteristics

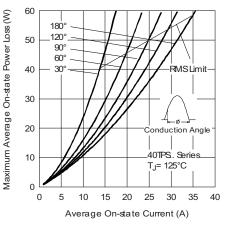


Fig. 3 - On-State Power Loss Characteristics

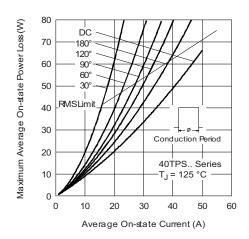


Fig. 4 - On-State Power Loss Characteristics

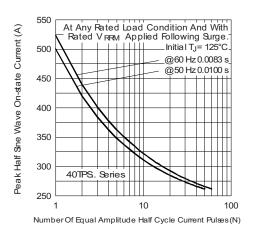
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Fig. 5 - Maximum Non-Repetitive Surge Current

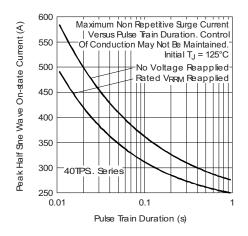


Fig. 6 - Maximum Non-Repetitive Surge Current

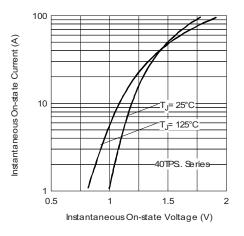


Fig. 7 - On-State Voltage Drop Characteristics

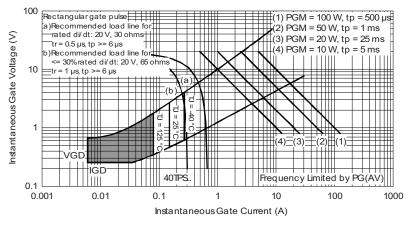


Fig. 8 - Gate Characteristics

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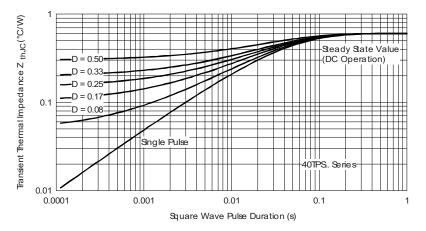


Fig. 9 - Thermal Impedance ZthJC Characteristics

ORDERING INFORMATION TABLE

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Device code	VS-	40	т	Р	S	16	PbF
		(2)	(3)	(4)	(5)	(6)	(7)
	<u> </u>	Vieł		vicondur	ctors pro	duct	Ŭ
	2 -		-	ng (40 =	-		
	3 -			iguratior	ו:		
	4 -		Thyristo kage:	or			
	-		TO-247				
	5 -		e of silic				
	6 -				ery recti = 1600 V		
	7 -		•	tal digit:		/	
		PbF	= Lead	(Pb)-fre	e and R	oHS co	mpliant
		-M3	= Halog	jen-free	, RoHS (complia	nt, and

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-40TPS16PbF	25	500	Antistatic plastic tubes					
VS-40TPS16-M3	25	500	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95223					
Part marking information	TO-247AC PbF	www.vishay.com/doc?95226					
	TO-247AC -M3	www.vishay.com/doc?95007					

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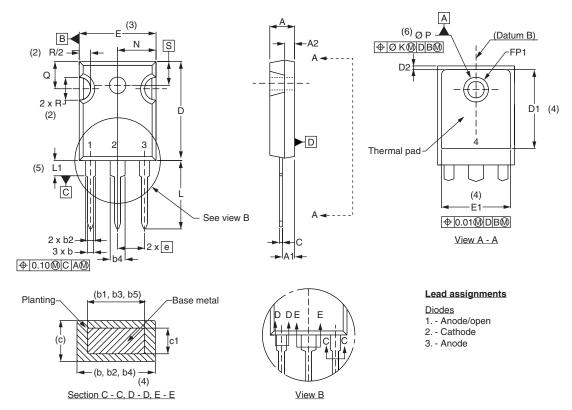
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Outline Dimensions





DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			FK	2.	54	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.37	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ΦР	3.56	3.66	0.14	0.144	
с	0.38	0.86	0.015	0.034			Φ Ρ1	-	6.98	-	0.275	
c1	0.38	0.76	0.015	0.030			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3]	R	4.52	5.49	1.78	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	' BSC	

Notes

- ⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC outline TO-247 with exception of dimension c

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